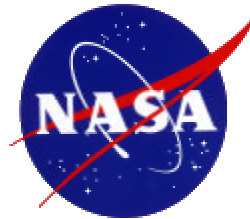


# Additive Effects on $\text{Si}_3\text{N}_4$ Oxidation/Volatilization in Combustion Environments

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Elizabeth Opila, Cleveland State University  
Dennis Fox, NASA Glenn Research Center  
Craig Robinson, Dynacs Engineering Co.



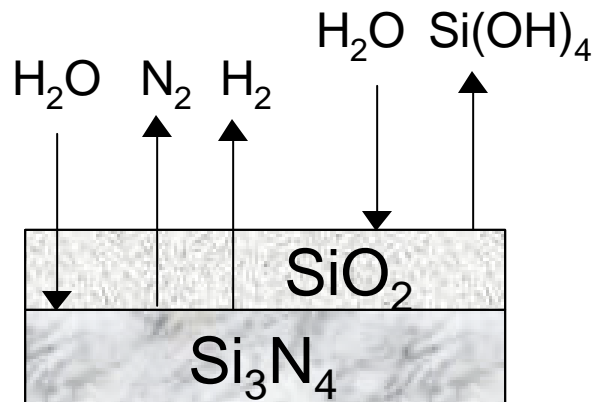
Richard Wenglarz, South Carolina Institute for Energy Studies  
Matt Ferber, Oak Ridge National Laboratory

DOE EBC Workshop  
November 6, 2002  
Nashville, TN

# Paralinear oxidation/volatilization of $\text{Si}_3\text{N}_4$ in water vapor

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- Parabolic oxidation reaction to form silica scale  
$$\text{Si}_3\text{N}_4 + 6\text{H}_2\text{O}(\text{g}) = 3\text{SiO}_2 + 2\text{N}_2(\text{g}) + 6\text{H}_2(\text{g})$$
- Linear volatilization reaction to remove silica scale  
$$\text{SiO}_2 + 2\text{H}_2\text{O}(\text{g}) = \text{Si}(\text{OH})_4(\text{g})$$



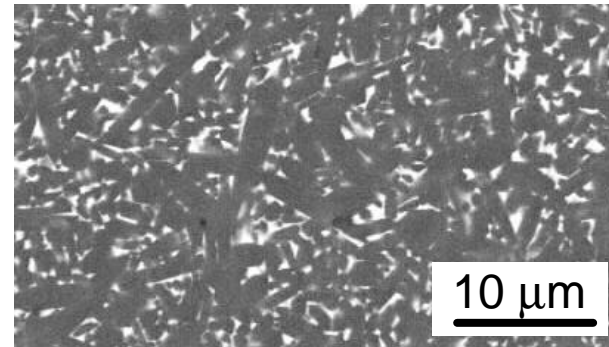
## Additives in $\text{Si}_3\text{N}_4$

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- Rare earth oxides added as sintering aids
- Additives present in grain boundary phase

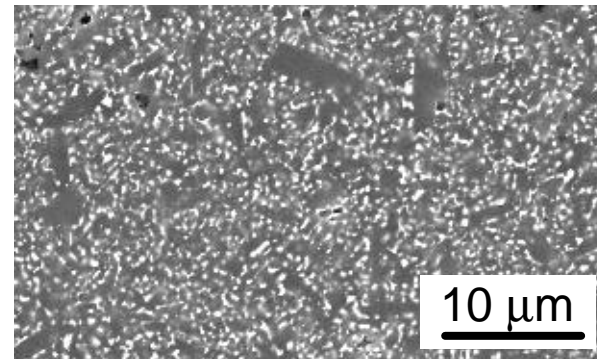
AS800, AlliedSignal

- $\text{La}_2\text{O}_3$ ,  $\text{Y}_2\text{O}_3$ , SrO additives
- $7\text{RE}_2\text{O}_3 \cdot 9\text{SiO}_2$  grain boundary phase



SN282, Kyocera

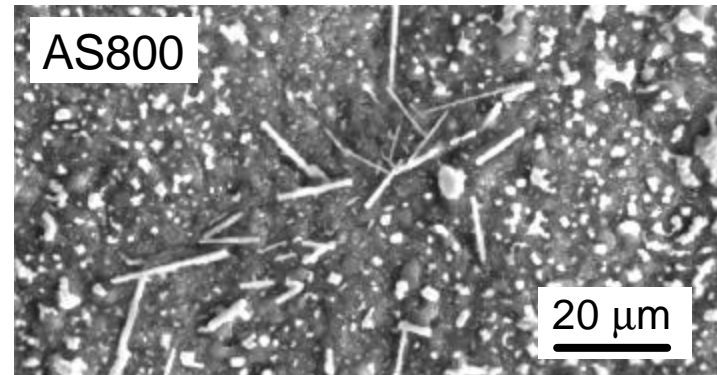
- $\text{Lu}_2\text{O}_3$  additive
- $\text{Lu}_2\text{Si}_2\text{O}_7$  and  $\text{Lu}_2\text{SiO}_5$  grain boundary phase



# Oxidation of $\text{Si}_3\text{N}_4$ with additives

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**In dry oxygen:**

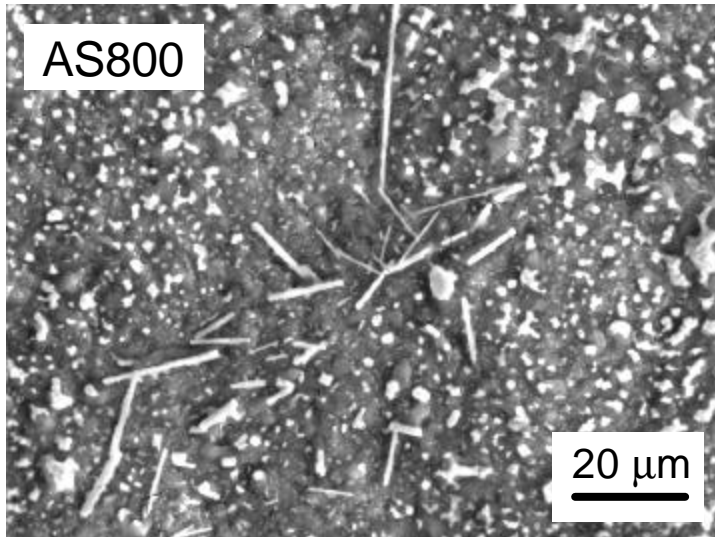


- Silica scale forms
- High aspect ratio  $\text{RE}_2\text{Si}_2\text{O}_7$  grains form on surface of scale
- Outward diffusion of RE cations control oxidation rate  
Cubicciotti and Lau, JECS, 126 [10] 1723 (1979).

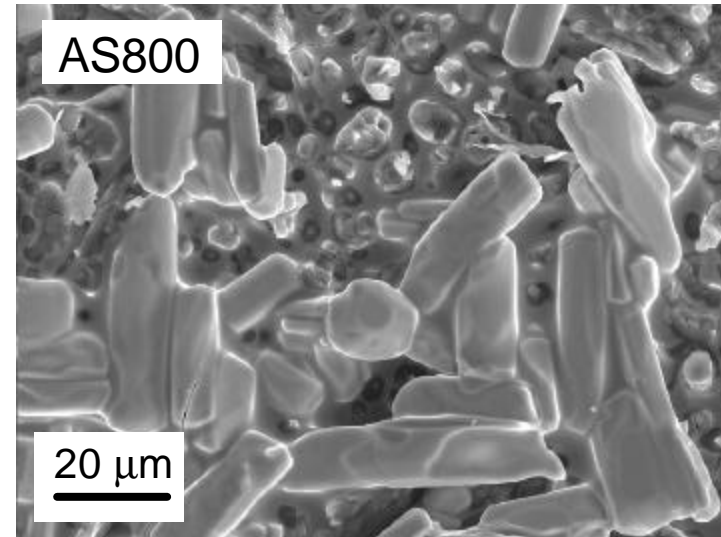
How does surface  $\text{RE}_2\text{Si}_2\text{O}_7$  formation affect volatility and recession in water vapor ?

# Effects of surface $\text{RE}_2\text{Si}_2\text{O}_7$ formation on volatility

- Preferential volatilization of silica
- Surface enrichment of  $\text{RE}_2\text{Si}_2\text{O}_7$



1300°C, 1 atm  $\text{O}_2$ , 100h, 0.4 cm/s



1300°C, 6 atm, 0.6 atm  $\text{H}_2\text{O}$ , 50h, 20 m/s

Do sintering additives offer an in situ opportunity for oxide surface modification that may lower volatility rate?

# Experimental

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- $\text{Si}_3\text{N}_4$  exposures, 1066-1400°C
  - TGA, 1 atm dry oxygen, 0.4 cm/s,
  - TGA, 1 atm, 0.5 atm  $\text{H}_2\text{O}$ , 4 cm/s,
  - HPBR, 6 atm, 0.6 atm  $\text{H}_2\text{O}$ , 20 m/s,
  - Turbine, 8.7 atm, 0.9 atm  $\text{H}_2\text{O}$ , 160-572 m/s  
Exxon, Mobile, AL - Rolls Royce - DOE Advanced Turbine Systems Program



Increasing  
 $\text{SiO}_2$  volatility

- Weight change/recession, XRD, SEM, EDS

# Si<sub>3</sub>N<sub>4</sub> exposed in TGA

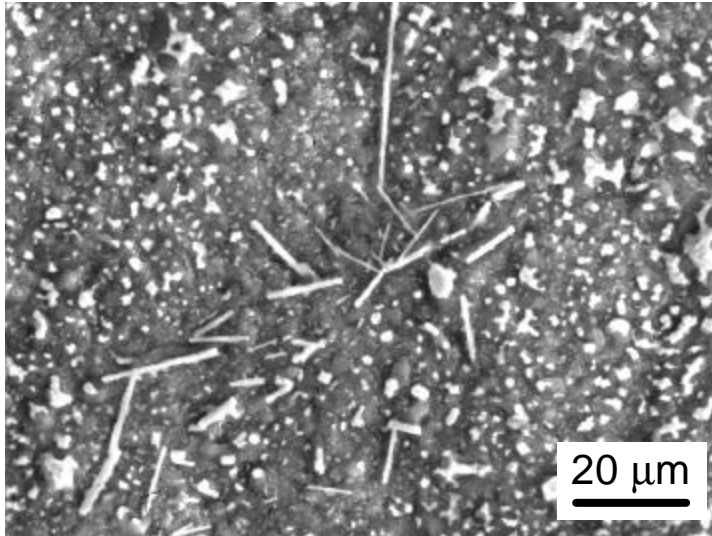
1300°C, 1 atm, dry oxygen, 0.4 cm/s, 100h

Oxidation, no volatilization

AS800

$$k_p = 3 \times 10^{-4} \text{ mg}^2/\text{cm}^4 \text{ h}$$

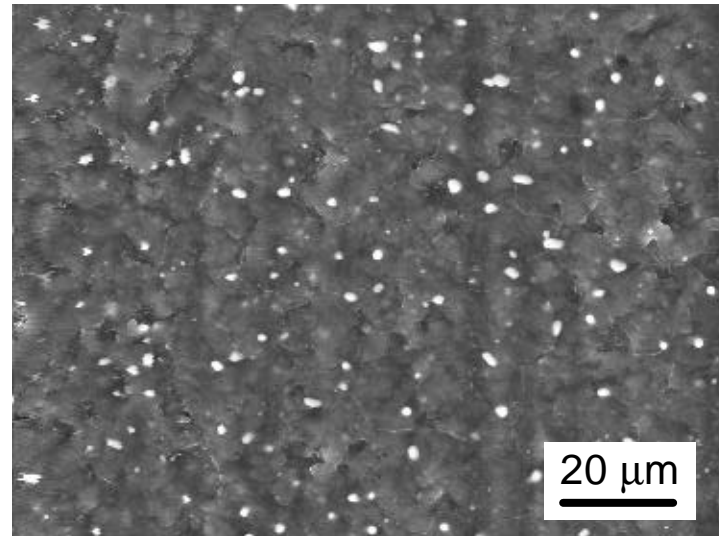
cristobalite, La<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>



SN282

$$k_p = 6 \times 10^{-5} \text{ mg}^2/\text{cm}^4 \text{ h}$$

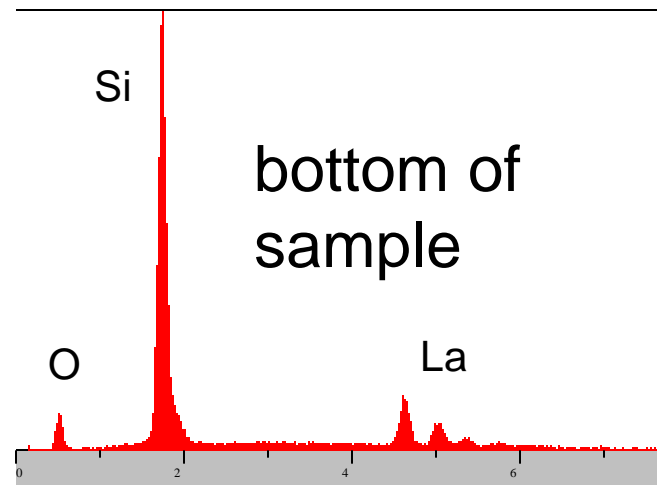
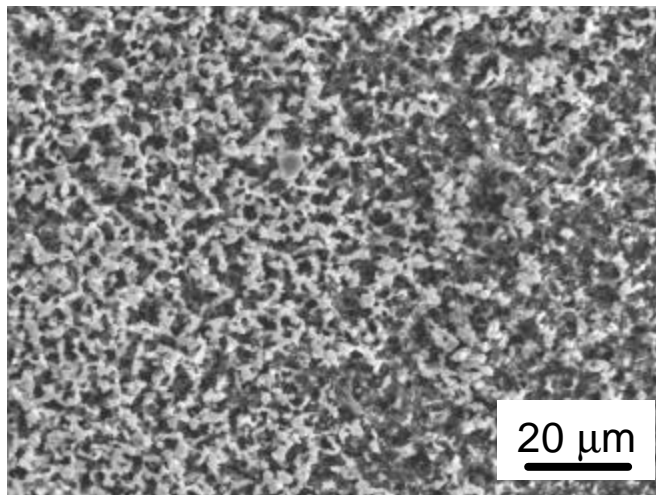
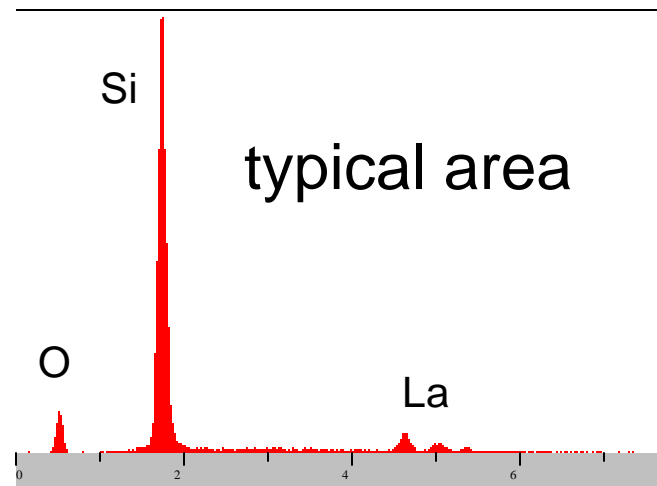
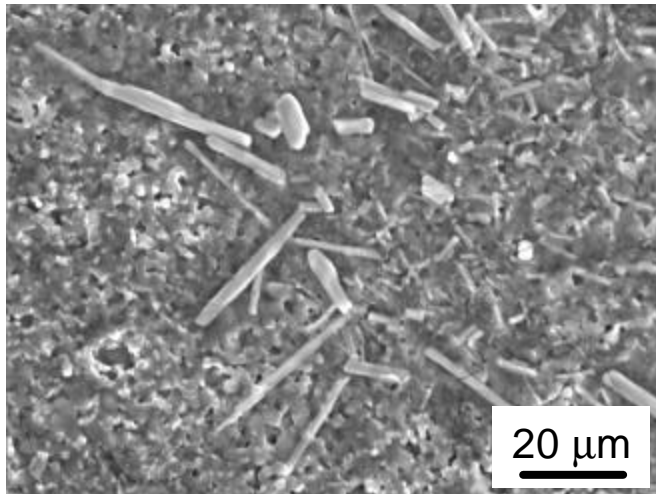
cristobalite, Lu<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>, Lu<sub>2</sub>SiO<sub>5</sub>



# AS800 exposed in TGA

1300°C, 1 atm, 0.5 atm H<sub>2</sub>O, 4.4 cm/s, 100h

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# Si<sub>3</sub>N<sub>4</sub> exposed in TGA

1300°C, 1 atm, 0.5 atm H<sub>2</sub>O, 4.4 cm/s, 100h

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## Paralinear oxidation/volatilization

AS800

$$k_p = 9 \times 10^{-4} \text{ mg}^2/\text{cm}^4 \text{ h}$$

$$k_l = 4 \times 10^{-3} \text{ mg}/\text{cm}^2 \text{ h}$$

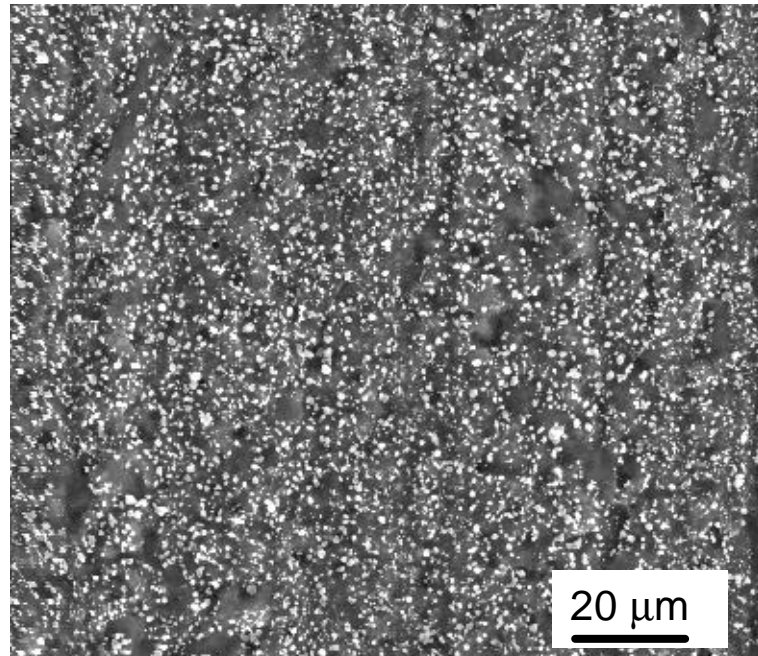
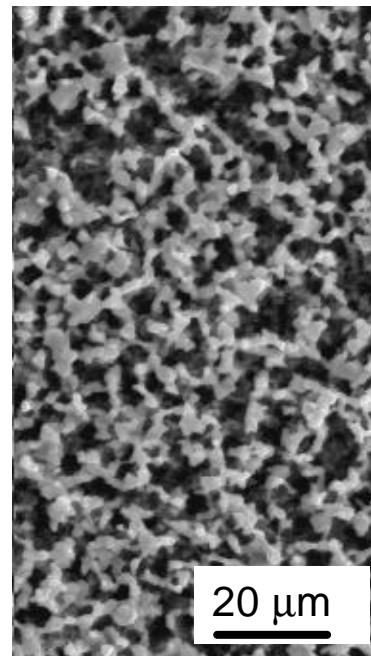
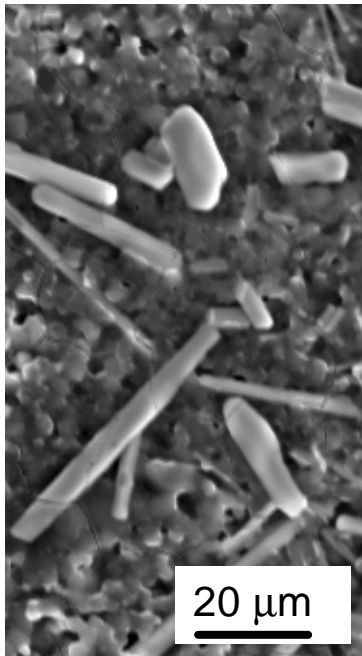
cristobalite, La<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>

SN282

$$k_p = 4 \times 10^{-4} \text{ mg}^2/\text{cm}^4 \text{ h}$$

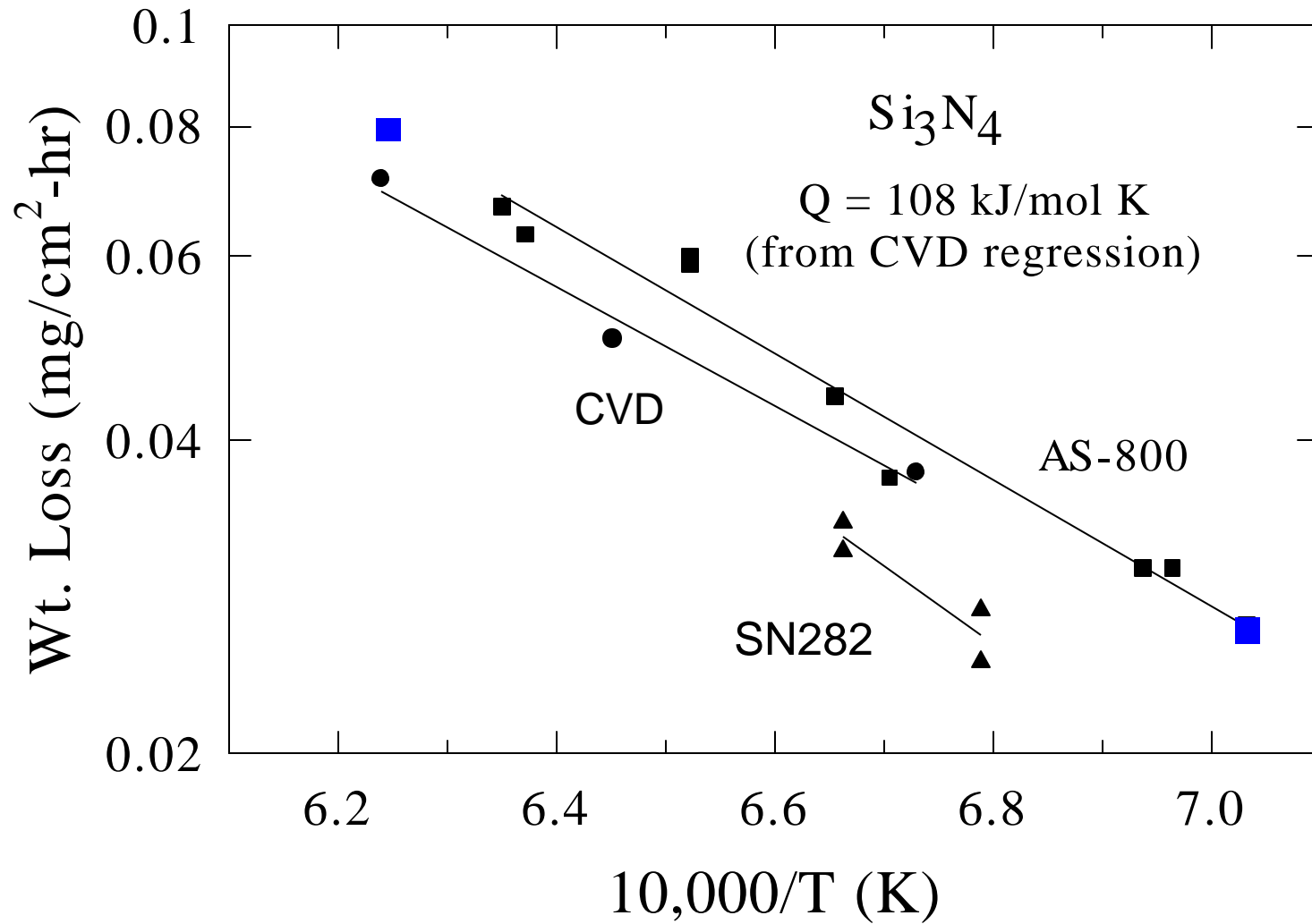
$$k_l = 2 \times 10^{-3} \text{ mg}/\text{cm}^2 \text{ h}$$

cristobalite, Lu<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>



# Si<sub>3</sub>N<sub>4</sub> exposed in HPBR

6 atm, 0.6 atm H<sub>2</sub>O, 20 m/s



# AS800 exposed in HPBR

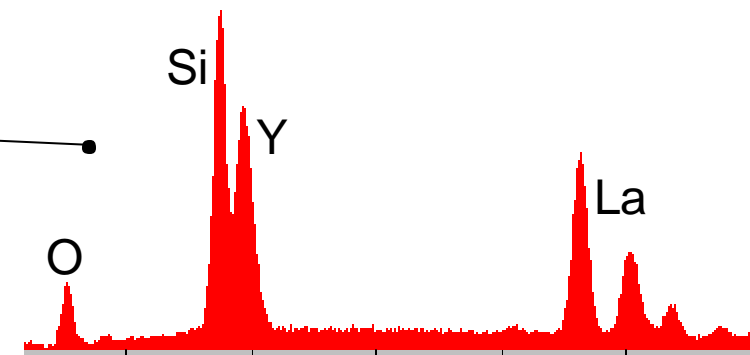
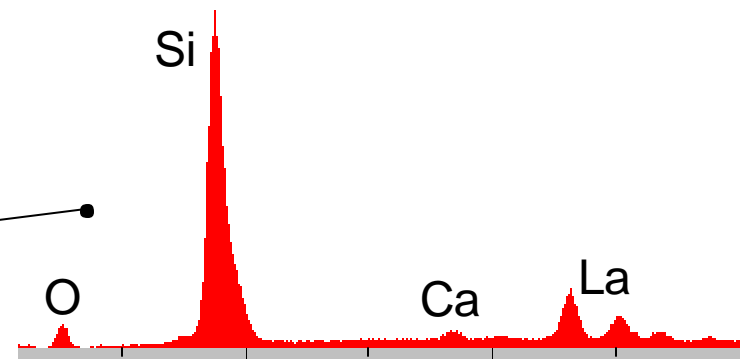
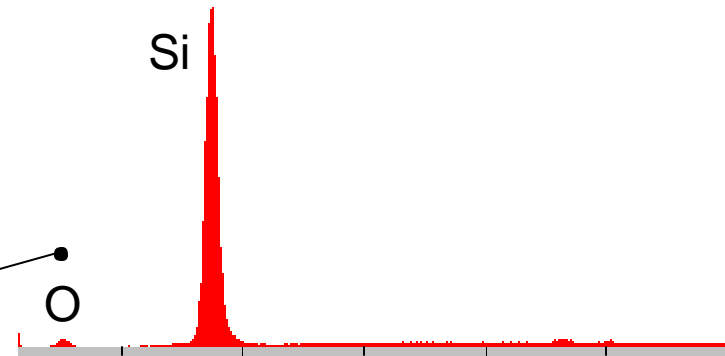
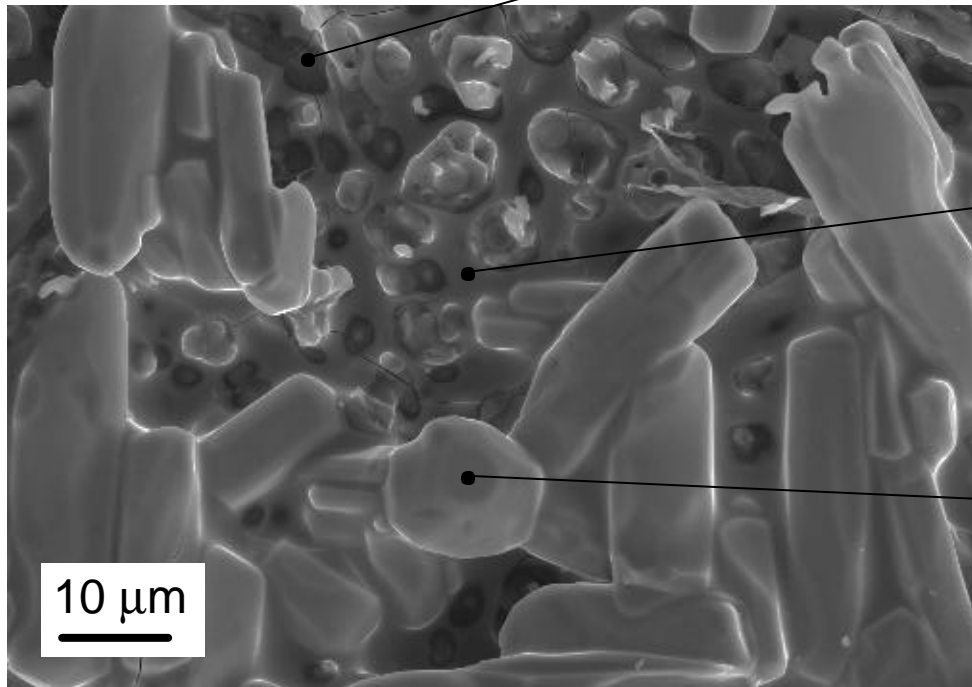
1300°C, 6 atm, 0.6 atm H<sub>2</sub>O, 20 m/s, 50h

## Oxidation/volatilization

$$k_p = 5 \times 10^{-2} \text{ mg}^2/\text{cm}^4 \text{ h}$$

$$k_l = 6 \times 10^{-2} \text{ mg}/\text{cm}^2 \text{ h}$$

cristobalite, La<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>, Y<sub>2</sub>O<sub>3</sub>?



# SN282 exposed in HPBR

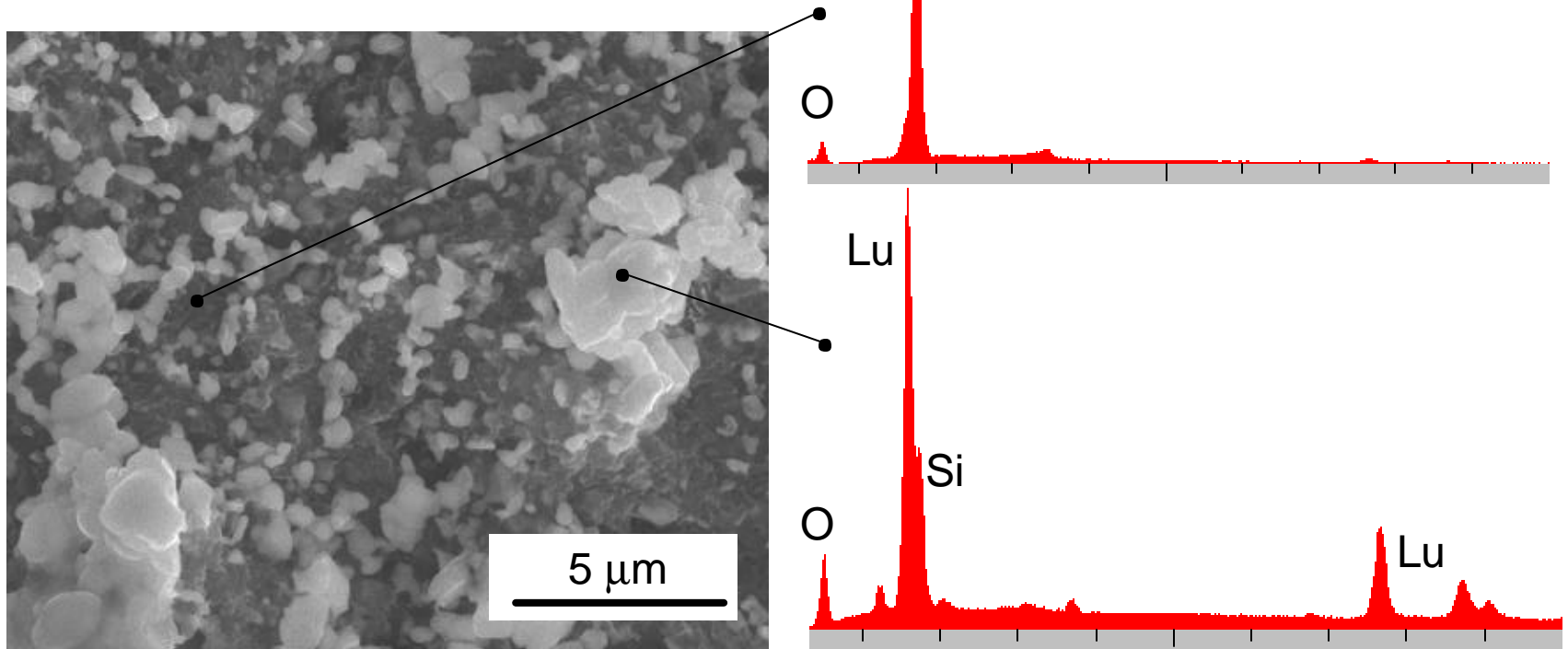
1225°C, 6 atm, 0.6 atm H<sub>2</sub>O, 20 m/s, 102h

## Oxidation/volatilization

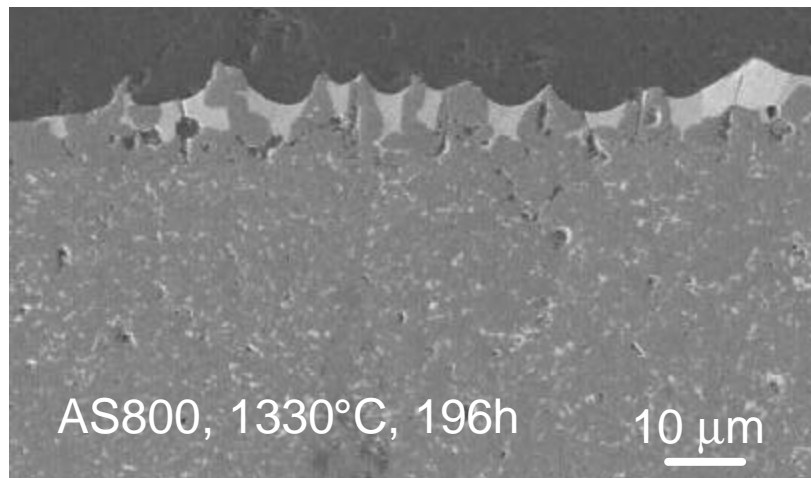
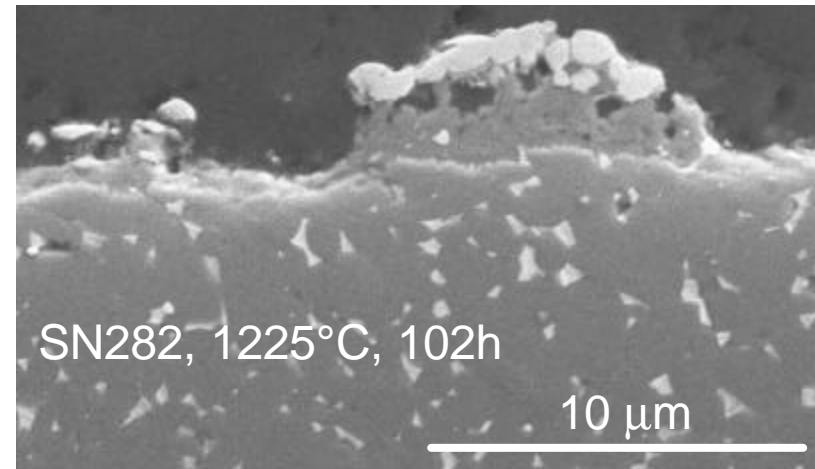
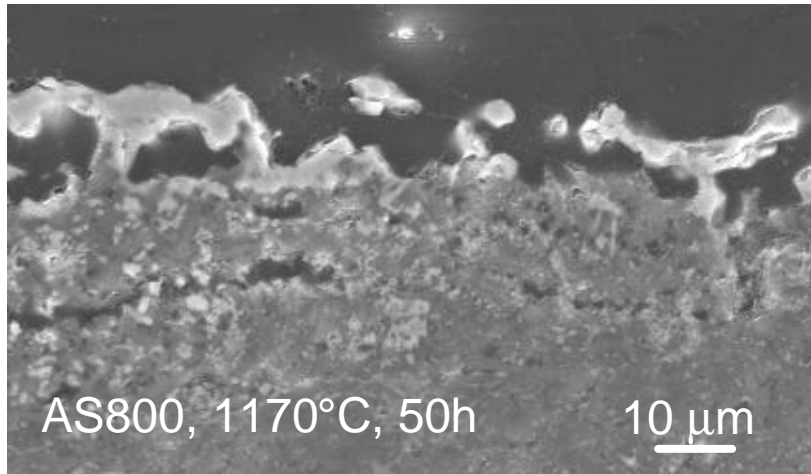
$k_p$  = not measured

$k_l = 3 \times 10^{-2}$  mg/cm<sup>2</sup> h

Lu<sub>2</sub>Si<sub>2</sub>O<sub>7</sub>, minor cristobalite, Lu<sub>2</sub>SiO<sub>5</sub>

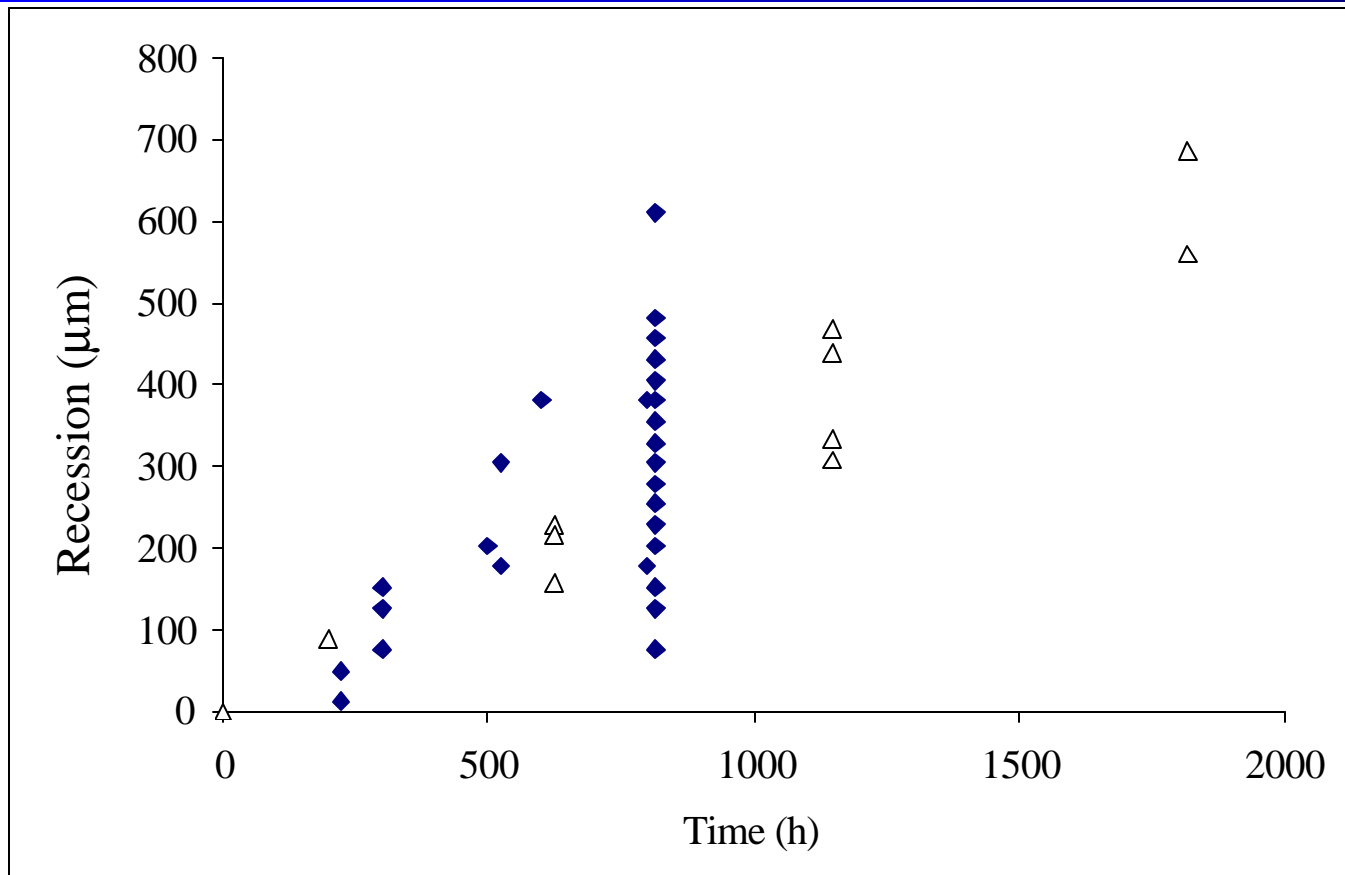


# Comparison of AS800 and SN282 exposed in HPBR 6 atm, 0.6 atm H<sub>2</sub>O, 20 m/s



- AS800
  - 1170°C: spalling of  $\text{La}_2\text{Si}_2\text{O}_7$ , sub-surface damage
  - 1330°C: low melting phase, does not protect  $\text{SiO}_2$
- SN282
  - 1225°C: “stalks” of  $\text{SiO}_2$  with  $\text{Lu}_2\text{Si}_2\text{O}_7$  on top

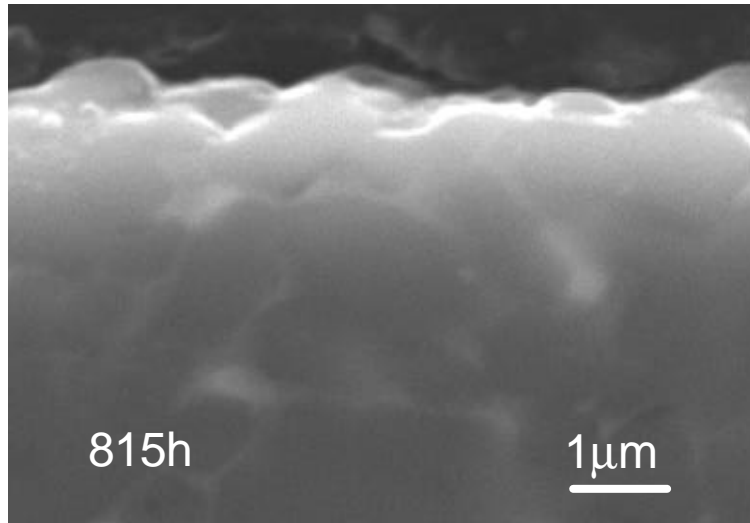
# Si<sub>3</sub>N<sub>4</sub> turbine vanes, 1066-1260°C, 8.7 atm, 0.9 atm H<sub>2</sub>O, 160-570 m/s



Comparison of trailing edge thickness values for uncoated AS800 ◆ and uncoated SN282 △. Courtesy Matt Ferber, ORNL - Rolls Royce ceramic vane program – DOE ATS Program.

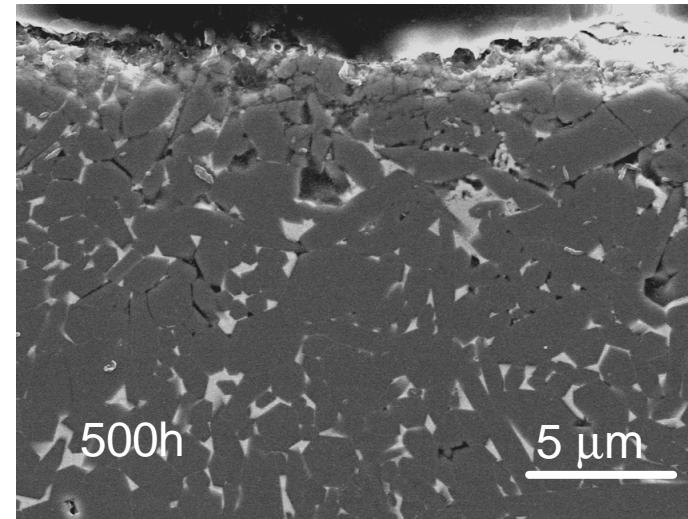
# AS800 turbine vane

1066-1260°C, 8.7 atm, 0.9 atm H<sub>2</sub>O, 160-570 m/s



No oxide found on surface by SEM. XRD indicates La<sub>2</sub>O<sub>3</sub> + Si<sub>3</sub>N<sub>4</sub>. No La<sub>2</sub>Si<sub>2</sub>O<sub>7</sub> found.

This vane was in a position where less oxidation and lower velocities were expected than elsewhere in turbine.



La<sub>2</sub>Si<sub>2</sub>O<sub>7</sub> or accumulated intergranular phase found on surface. Subsurface damage.

Photo courtesy of Matt Ferber, ORNL

## SN282 turbine vane

1066-1260°C, 8.7 atm, 0.9 atm H<sub>2</sub>O, 160-570 m/s, 1148h

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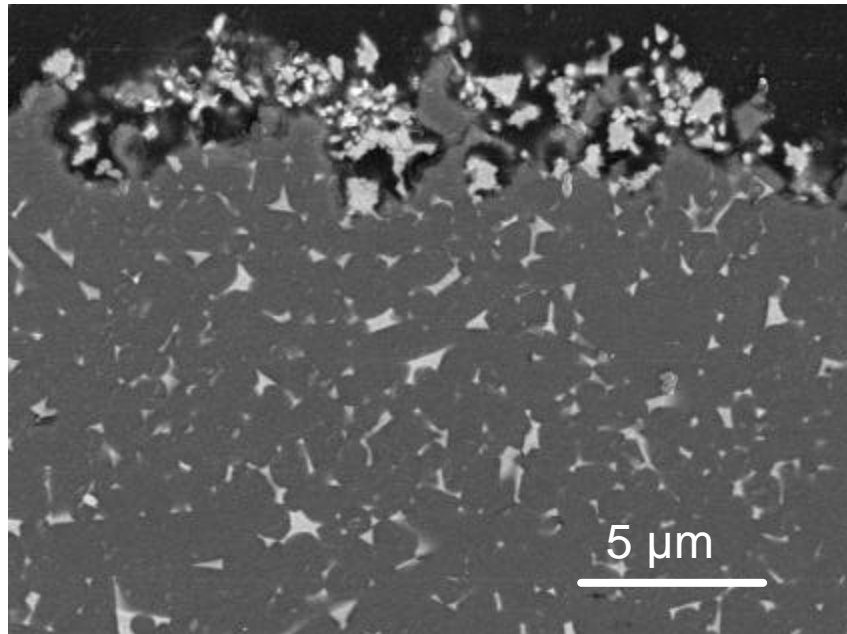


Photo courtesy  
Matt Ferber, ORNL

Accumulation of Lu<sub>2</sub>Si<sub>2</sub>O<sub>7</sub> at vane surface



# Summary

---

- AS800
  - Weight loss and recession rates same as pure  $\text{Si}_3\text{N}_4$
  - $T < 1300^\circ\text{C}$ : poorly adherent surface acicular grains of  $(\text{La}, \text{Y})_2\text{Si}_2\text{O}_7$  formed
  - $T > 1300^\circ\text{C}$ : low melting phase also formed
  - High velocity: surface oxide generally missing,  $\text{La}_2\text{O}_3$  detected
  - Subsurface grain boundary damage occurred
- SN282
  - Weight loss and recession rates about half that of pure  $\text{Si}_3\text{N}_4$  and AS800
  - Small, spherical  $\text{Lu}_2\text{Si}_2\text{O}_7$  particles found on surface
  - $\text{Lu}_2\text{Si}_2\text{O}_7$  particles may be more adherent than  $(\text{La}, \text{Y})_2\text{Si}_2\text{O}_7$  grains on AS800
  - Subsurface grain boundary damage not observed

## Factors which affect in situ surface modification of $\text{Si}_3\text{N}_4$ by RE additions

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- Cation mobility effects
- CTE match between RE silicate, silica and  $\text{Si}_3\text{N}_4$
- Phase stability of  $\text{RE}_2\text{Si}_2\text{O}_7$
- Silica activity of  $\text{RE}_2\text{Si}_2\text{O}_7$

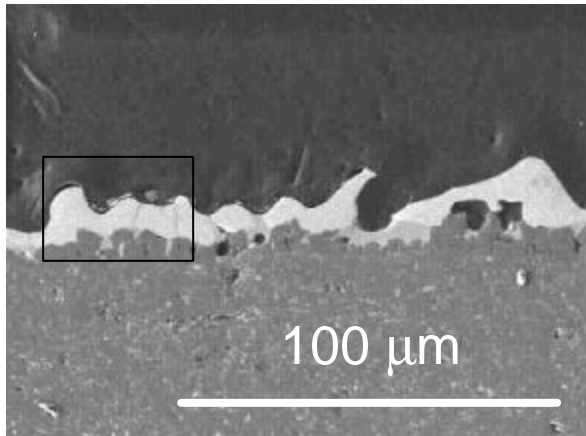
# Cation mobility effects on in situ surface modification of $\text{Si}_3\text{N}_4$ by RE additions

- Cation diffusivity increases relative to silica growth rate as temperature increases.
  - Larger  $\text{RE}_2\text{Si}_2\text{O}_7$  grains on oxide surface as temperature increases. Demonstrated for Yb in SN362, Kyocera (Lee and Readey, J Am Cer Soc. 85 [6] 1435-1440, 2002)
- Cation mobility for  $\text{Lu} < \text{La}$ . Due to different grain boundary phases in AS800 and SN282?
  - $\text{Si}_3\text{N}_4$  oxidation rates lower for  $\text{Lu}_2\text{O}_3$  additions than for  $\text{La}_2\text{O}_3$  additions
  - Less  $\text{RE}_2\text{Si}_2\text{O}_7$  found on surface in SN282 than on AS800
  - Depletion of RE from grain boundary phase leads to subsurface damage, cracking in AS800 but not in SN282 (Ferber)

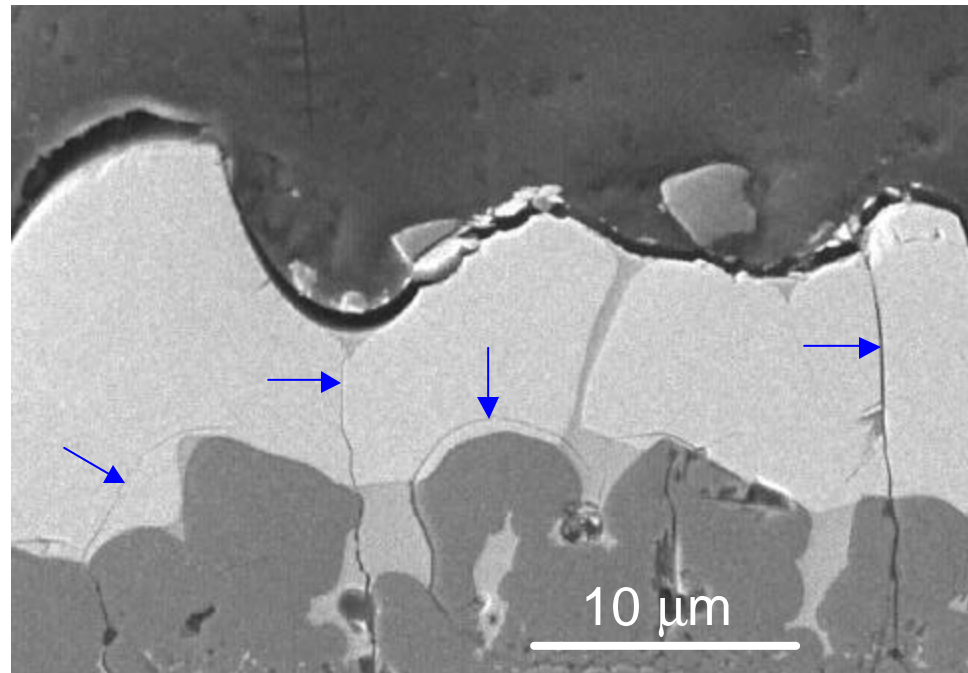
Balance desired formation of surface  $\text{RE}_2\text{Si}_2\text{O}_7$  with undesirable subsurface grain boundary depletion.

# CTE effects on in situ surface modification of $\text{Si}_3\text{N}_4$ by RE additions

- Possible CTE mismatch between  $\text{La}_2\text{Si}_2\text{O}_7$ ,  $\text{SiO}_2$ , and  $\text{Si}_3\text{N}_4$
- No cracks observed for  $\text{Lu}_2\text{Si}_2\text{O}_7$
- Unable to find CTE values for  $\text{RE}_2\text{Si}_2\text{O}_7$  in open literature

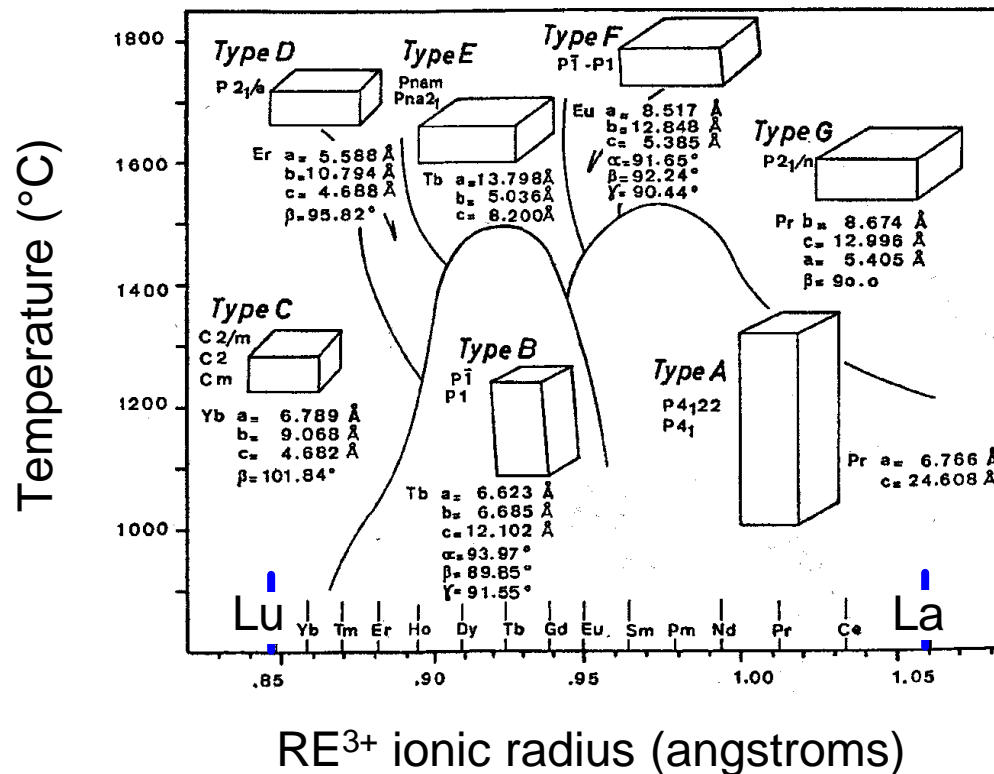


AS800, HPBR, 1330°C, 196h

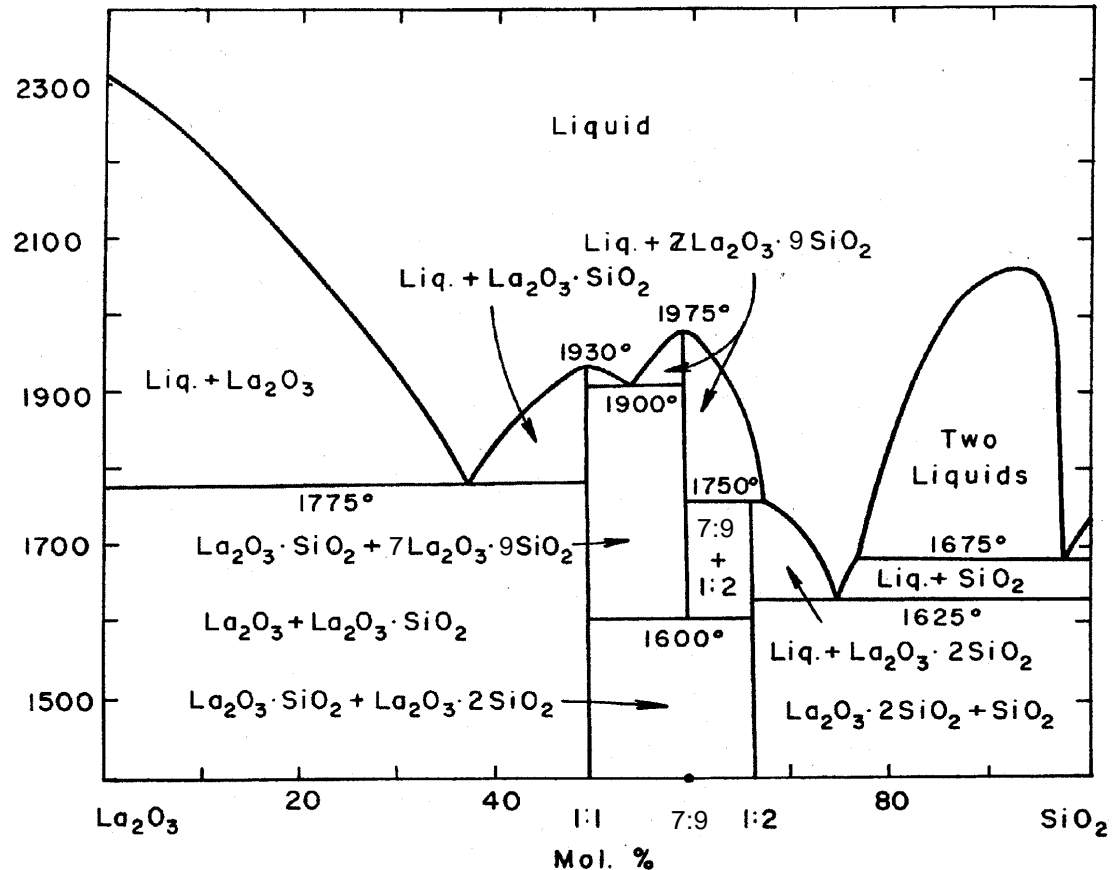


# Phase stability effects on in situ surface modification of $\text{Si}_3\text{N}_4$ by RE additions

- Reconstructive phase transformations of  $\text{RE}_2\text{Si}_2\text{O}_7$  occur between 1200-1500°C  
(J. Felsche, Structure and Bonding 13, Rare Earths, 1973.)



# Silica activity effects on in situ surface modification of $\text{Si}_3\text{N}_4$ by RE additions



I.A. Bondar,  
Cer.Int. 8 [3] 83 (1982)

Silica activity in this system nearly ideal. A factor of two reduction in silica volatility expected for  $\text{RE}_2\text{Si}_2\text{O}_7$ .

# Summary

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- AS800 in combustion environments
  - Weight loss/recession at least as great as CVD  $\text{Si}_3\text{N}_4$
  - $T < 1300^\circ\text{C}$ 
    - $\text{La}_2\text{Si}_2\text{O}_7$  spalls off
    - Subsurface damage
  - $T > 1300^\circ\text{C}$ 
    - Low melting phase forms
    - Melt phase does not protect  $\text{SiO}_2$
  - High velocity
    - $\text{La}_2\text{Si}_2\text{O}_7$  decomposes to  $\text{La}_2\text{O}_3$
    - Bare  $\text{Si}_3\text{N}_4$  observed

# Summary

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- SN282 in combustion environments
  - Volatility/recession reduced by a factor of two relative to CVD  $\text{Si}_3\text{N}_4$  and AS800
  - Partial surface coverage by  $\text{Lu}_2\text{Si}_2\text{O}_7$
  - $\text{Lu}_2\text{Si}_2\text{O}_7$  may offer slight protection from volatility to underlying silica at moderate to high velocities



# Conclusions

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- In combustion environments preferential volatilization of silica and surface enrichment of  $\text{RE}_2\text{Si}_2\text{O}_7$  has been observed for  $\text{Si}_3\text{N}_4$  containing RE additives.
- Factor of two reduction in weight loss and recession rates observed for SN282 in combustion environments may be due to reduction in silica volatility by enrichment of  $\text{Lu}_2\text{Si}_2\text{O}_7$  surface phase.

# Conclusions

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- Factors which affect in situ formation of an adherent  $\text{RE}_2\text{Si}_2\text{O}_7$  phase have been identified.
  - RE mobility: balance  $\text{RE}_2\text{Si}_2\text{O}_7$  surface coverage with grain boundary depletion. Dependent on temperature, RE cation, and grain boundary phase.
  - CTE match of  $\text{RE}_2\text{Si}_2\text{O}_7$  with  $\text{SiO}_2$  and  $\text{Si}_3\text{N}_4$
  - $\text{RE}_2\text{Si}_2\text{O}_7$  phase stability: Yb-, Lu-disilicates most stable
  - Ideal silica activity limits protective capability of in situ formed  $\text{RE}_2\text{Si}_2\text{O}_7$  surfaces.
- EBC's needed for long-term application of additive-containing  $\text{Si}_3\text{N}_4$  in combustion environments.

# Acknowledgments

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- Ralph Garlick, XRD
- TGA  
Don Humphrey  
Susan Lewton  
QuynhGiao Nguyen